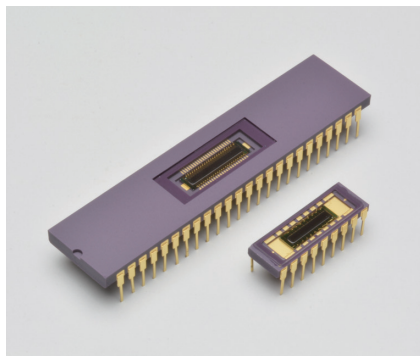


# InAsSb photovoltaic detector arrays



P15742 series

**16, 46 element array capable of detecting up to 5  $\mu\text{m}$  band**

The P15742 series is one-dimensional InAsSb photovoltaic detector array in a ceramic DIP (dual inline package). They have a back-illuminated structure that achieves low crosstalk. These are environmentally friendly infrared detectors that do not use lead, mercury, or cadmium, which are substances restricted by the RoHS Directive.

## Features

- High sensitivity
- Low crosstalk
- RoHS compliant (lead, mercury, cadmium free)

## Applications

- Infrared spectrophotometry
- Temperature measurement
- Remote sensing

## Structure

Parameter	P15742-016DS	P15742-046DS	Unit
Number of elements	16	46	-
Element size	0.45 × 0.7	0.2 × 0.7	mm
Element pitch	0.5	0.25	mm
Package	18-pin ceramic DIP	48-pin ceramic DIP	-
Window material	Sapphire		-

## Absolute maximum ratings (Ta=25 °C, unless otherwise noted)

Parameter	Symbol	Condition	Value	Unit
Reverse voltage	VR		1	V
Operating temperature	Topr	No dew condensation*1	-20 to +70	°C
Storage temperature	Tstg	No dew condensation*1	-20 to +80	°C

\*1: When there is a temperature difference between a product and the surrounding area in high humidity environments, dew condensation may occur on the product surface. Dew condensation on the product may cause deterioration in characteristics and reliability.

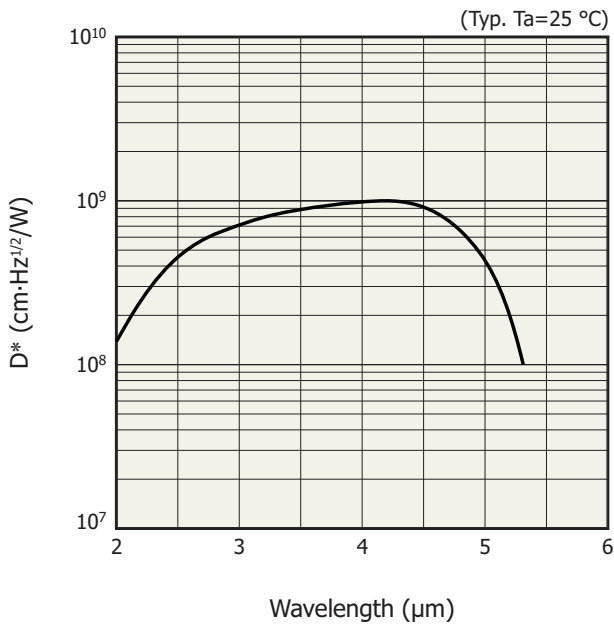
Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

## Electrical and optical characteristics (Ta=25 °C, per element)

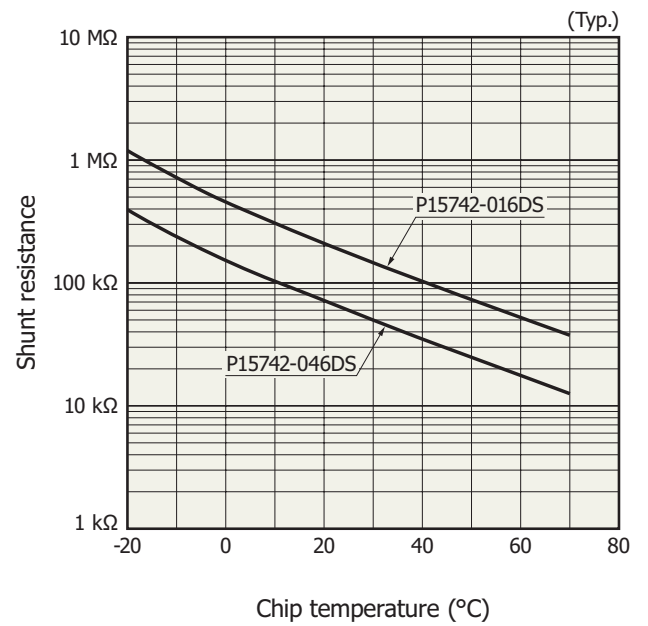
Parameter	Symbol	Condition	P15742-016DS			P15742-046DS			Unit
			Min.	Typ.	Max.	Min.	Typ.	Max.	
Peak sensitivity wavelength	$\lambda_p$		-	4.1	-	-	4.1	-	$\mu\text{m}$
Cutoff wavelength	$\lambda_c$		5	5.3	-	5	5.3	-	$\mu\text{m}$
Photosensitivity	S	$\lambda = \lambda_p$	5	6.5	-	11.6	14.6	-	mA/W
Shunt resistance	Rsh	VR=10 mV	70	180	-	24	60	-	k $\Omega$
Detectivity	D*	( $\lambda_p$ , 1200, 1)	$8 \times 10^8$	$1 \times 10^9$	-	$8 \times 10^8$	$1 \times 10^9$	-	cm <sup>2</sup> Hz <sup>1/2</sup> /W
Rise time	tr	VR=0 V, RL=50 $\Omega$ 10 to 90%, $\lambda=1.55 \mu\text{m}$	-	15	-	-	15	-	ns
Terminal capacitance	Ct	VR=0 V, f=1 MHz	-	40	-	-	50	-	pF
Noise equivalent power	NEP	$\lambda = \lambda_p$	-	$5.6 \times 10^{-11}$	$7 \times 10^{-11}$	-	$4.2 \times 10^{-11}$	$5.3 \times 10^{-11}$	W/Hz <sup>1/2</sup>

Note: Uniform irradiation on the entire photosensitive area

**Spectral response**

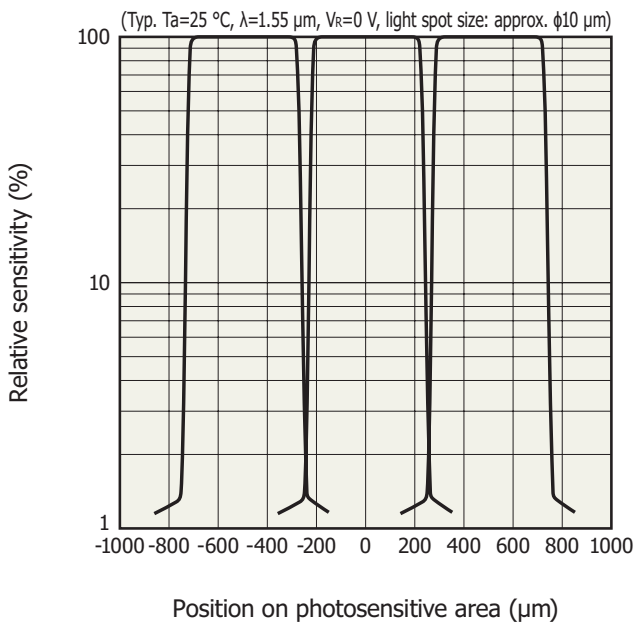


**Shunt resistance vs. chip temperature**

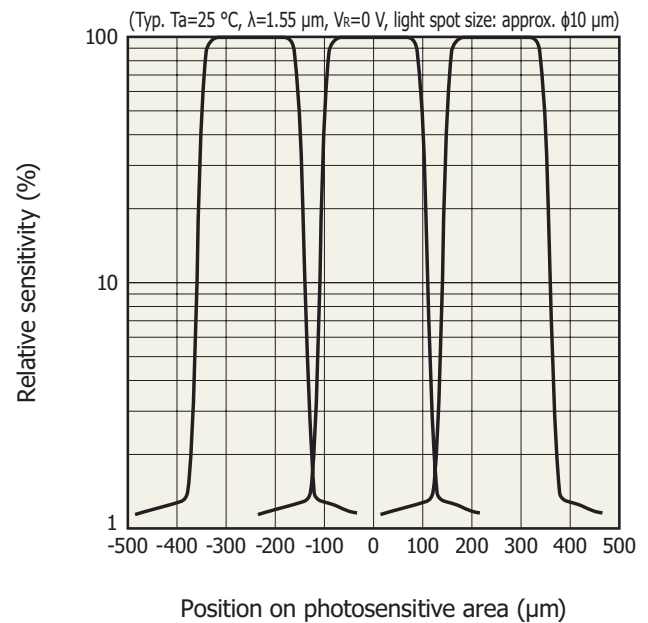


**Crosstalk characteristics**

P15742-016DS

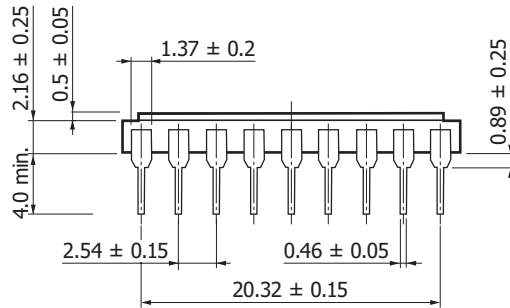
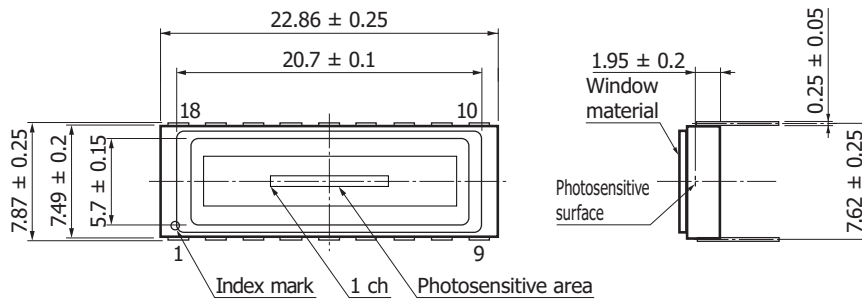


P15742-046DS



Dimensional outlines (unit: mm)

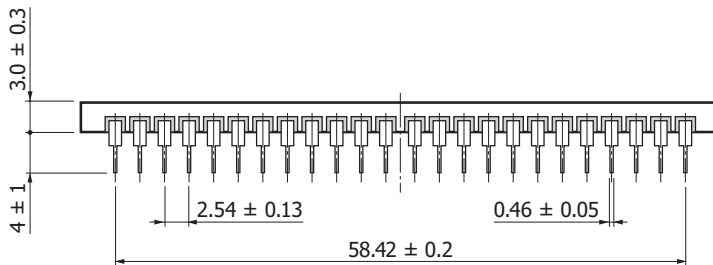
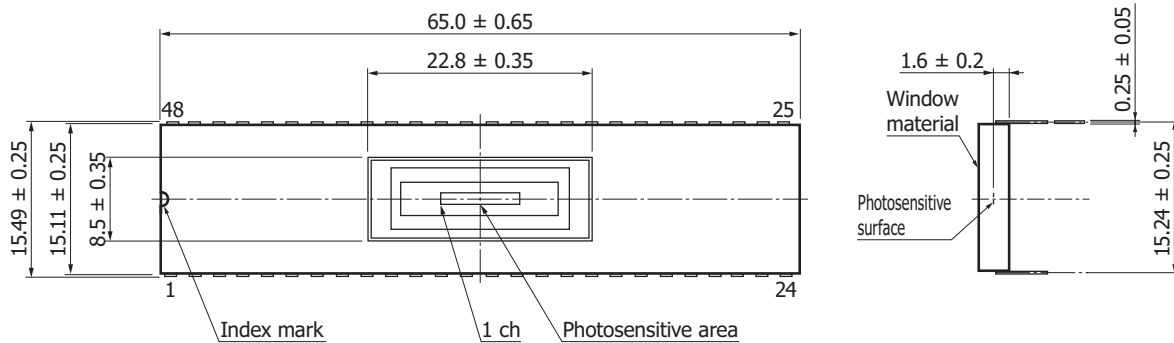
P15742-016DS



Chip position accuracy with respect to package center  
 $X, Y \leq \pm 0.3, \theta \leq \pm 3^\circ$

KIRDA0270EA

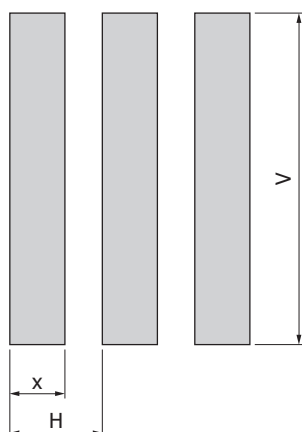
P15742-046DS



Chip position accuracy with respect to package center  
 $X, Y \leq \pm 0.3, \theta \leq \pm 3^\circ$

KIRDA0271EA

▣ Details of photosensitive area (unit: mm)



Number of elements	x	H	V
16	0.45	0.5	0.7
46	0.2	0.25	

KIRDC0131EA

▣ Pin connections

Pin no.	P15742-016DS	P15742-046DS	Pin no.	P15742-016DS	P15742-046DS
1	KC	KC	25		KC
2	2	2	26		45
3	4	4	27		43
4	6	6	28		41
5	8	8	29		39
6	10	10	30		37
7	12	12	31		35
8	14	14	32		33
9	16	16	33		31
10	KC	18	34		29
11	15	20	35		27
12	13	22	36		25
13	11	24	37		23
14	9	26	38		21
15	7	28	39		19
16	5	30	40		17
17	3	32	41		15
18	1	34	42		13
19		36	43		11
20		38	44		9
21		40	45		7
22		42	46		5
23		44	47		3
24		46	48		1

Note: KC: cathode (common), other than cathode: anode

### Recommended soldering conditions

Solder temperature: 260°C (5 s or less, once)

Solder the leads at a point at least 1.5mm away from the package body.

Note: When you set soldering conditions, check that problems do not occur in the product by testing out the conditions in advance.

### Related information

[www.hamamatsu.com/sp/ssd/doc\\_en.html](http://www.hamamatsu.com/sp/ssd/doc_en.html)

#### ■ Precautions

- Disclaimer
- Safety consideration
- Compound opto-semiconductors (photosensors, light emitters)

#### ■ Technical note

- Compound semiconductor photosensors

Information described in this material is current as of September 2023.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

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